PS9009

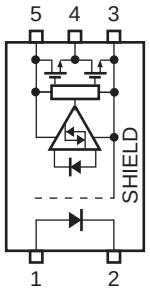
R08DS0133EJ0200
Rev.2.00
Mar 11, 2016

LOW IF TOTEM POLE OUTPUT TYPE HIGH CMR, IPM DRIVER, 5-PIN SSOP (LSO5) PHOTOCOUPLER

DESCRIPTION

The PS9009 is optical coupled high-speed, totem pole output (active high output type) isolators containing a GaAlAs LED on the input side and a photodiode and a signal processing circuit on the output side on one chip.
The PS9009 is specified high CMR and pulse width distortion with operating temperature. It is suitable for IPM (Intelligent Power Module) drive.

PIN CONNECTION
(Top View)



1. Anode
2. Cathode
3. GND
4. V_O
5. V_{CC}

FEATURES

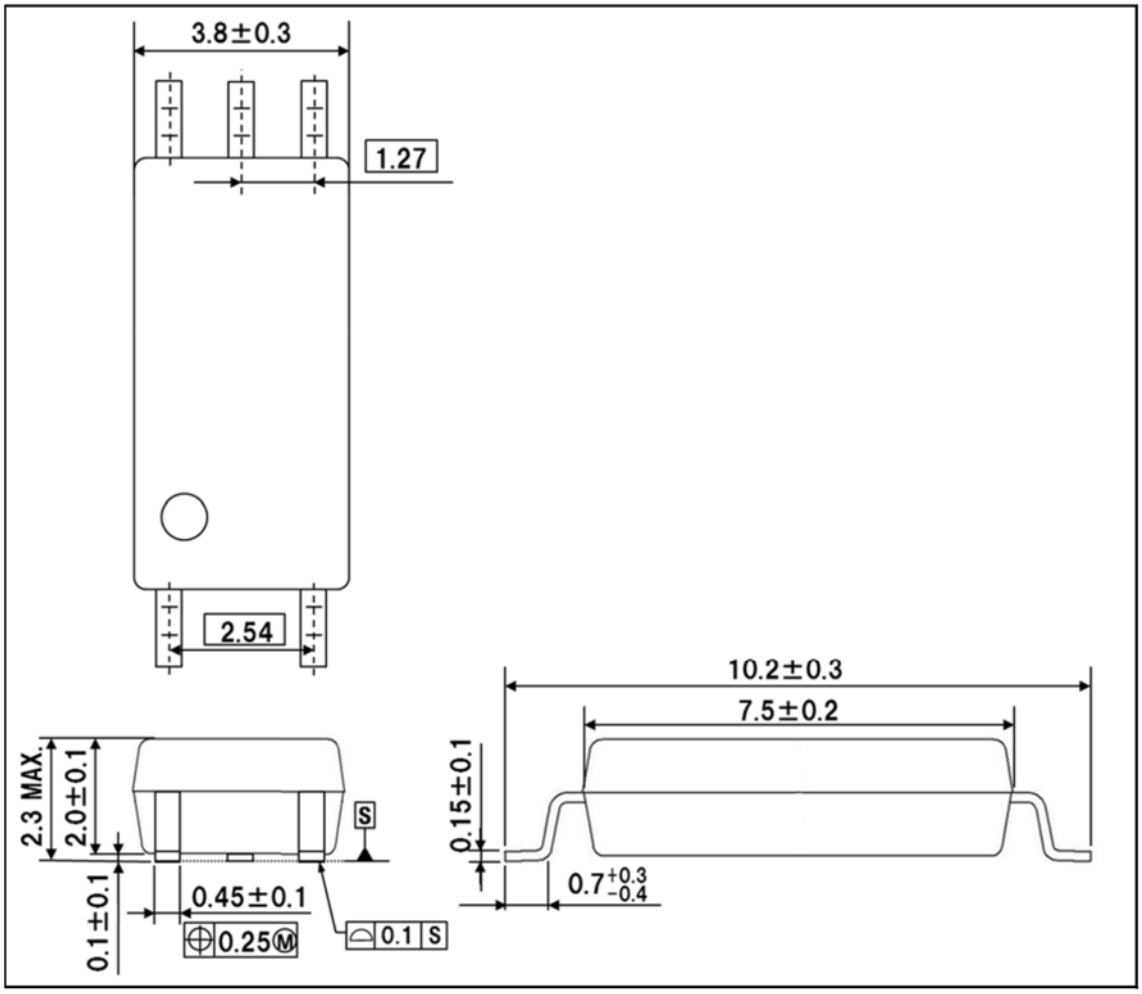
- Long creepage distance (8 mm MIN.)
- Totem pole output (Active High Output Type)
- Pulse width distortion ($|t_{PLH} - t_{PHL}|$ = 80 ns MAX.)
- High common mode transient immunity (CM_H, CM_L = ±50 kV/μs MIN.)
- Operating Ambient Temperature (125 °C MAX.)
- High isolation voltage (BV = 5 000 Vr.m.s.)
- Embossed tape product : PS9009-F3: 3 000 pcs/reel
- Pb-Free product
- Safety standards
  - UL approved: UL1577, Double protection
  - CSA approved: CA5A, CAN/CSA-C22.2 60065, CAN/CSA-C22.2 60950-1, Reinforced insulation)
  - VDE approval: DIN EN 60747-5-5 (Option)

APPLICATIONS

- IPM Driver
- General purpose inverter

Start of mass production
Oct.2015

PACKAGE DIMENSIONS (UNIT: mm)

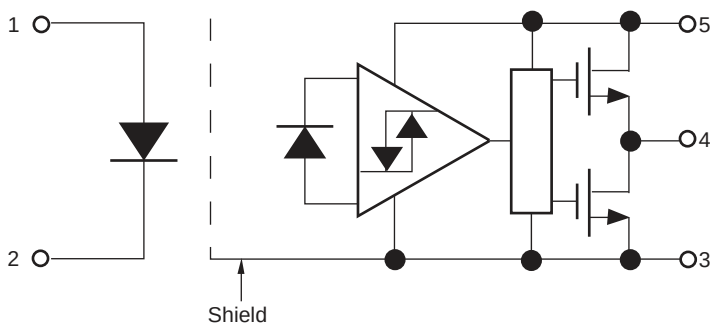


Weight：0.119g (typ.)

PHOTOCOUPLER CONSTRUCTION

Parameter	MIN.
Air Distance	8 mm
Outer Creepage Distance	8 mm
Isolation Distance	0.15 mm

BLOCK DIAGRAM



LED	Output
ON	H
OFF	L

MARKING EXAMPLE

R		An initial of "Renesas"
9009		Product Part Number
○		No.1 pin Mark, Anode Mark
N340	N	Rank Code
	340	Assembly Lot
	3	Last one-digit of Assembly Year
	40	Weekly Serial Code

ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number*1
PS9009	PS9009-Y-AX	Pb-Free and Halogen Free (Ni/Pd/Au)	20 pcs (Tape 20 pcs cut)	Standard products (UL,CSA approved)	PS9009
PS9009-F3	PS9009-Y-F3-AX		Embossed Tape 3 000 pcs/reel		
PS9009-V	PS9009-Y-V-AX		20 pcs (Tape 20 pcs cut)	UL,CSA approved DIN EN 60747-5-5 (VDE 0884-5): 2011-11 approved (Option)	
PS9009-V-F3	PS9009-Y-V-F3-AX		Embossed Tape 3 000 pcs/reel		

Note: *1. For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current*1	I_F	25	mA
	Reverse Voltage	V_R	5	V
Detector	Supply Voltage	V_{CC}	−0.5 to +25	V
	Output Voltage	V_O	−0.5 to +25	V
	Output Current	I_O	25	mA
	Power Dissipation*2	P_C	250	mW
Isolation Voltage *3		BV	5 000	Vr.m.s.
Operating Ambient Temperature		T_A	−40 to +125	°C
Storage Temperature		T_{stg}	−55 to +150	°C

Notes: *1. Reduced to 0.38 mA/°C at T_A = 85°C or more.
*2. Reduced to 4.0 mW/°C at T_A = 85°C or more
*3. AC voltage for 1 minute at T_A = 25°C, RH = 60% between input and output.
Pins 1-3 shorted together, 4-6 shorted together.

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Supply Voltage	V_{CC}	4.5	15	20	V
Output Voltage	V_O	0		20	V
Forward Current (ON)	$I_{F\ (ON)}$	5		10	mA
Forward Voltage (OFF)	$V_{F\ (OFF)}$	0		0.8	V
Operating Ambient Temperature	T_A	−40		125	°C

ELECTRICAL CHARACTERISTICS (T_A = –40 to +125°C, V_{CC} = 4.5 to 20 V, unless otherwise specified)

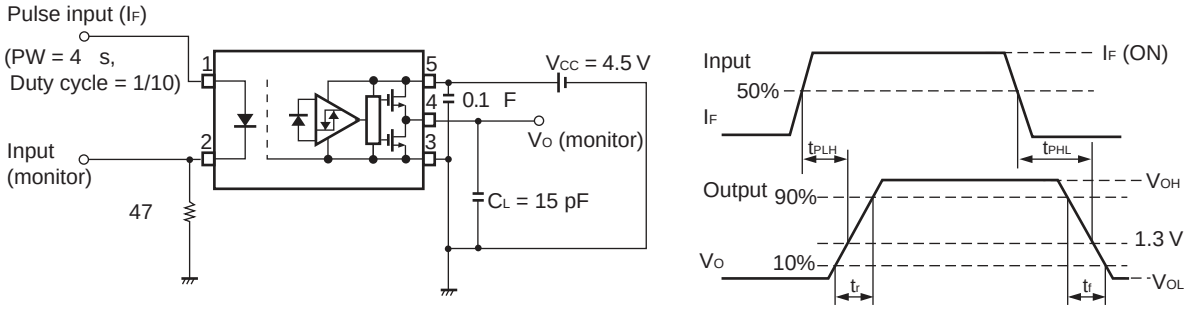
Parameter		Symbol	Conditions	MIN.	TYP.*1	MAX.	Unit
Diode	Forward Voltage	V_F	I_F = 10 mA, T_A = 25°C	1.3	1.56	1.8	V
	Reverse Current	I_R	V_R = 3 V, T_A = 25°C			10	μA
	Input Capacitance	C_t	V_F = 0 V, f = 1 MHZ, T_A = 25°C		30		pF
Detector	High Level Output Voltage	V_{OH}	V_{CC} = 4.5 V, I_O = –2.6 mA, I_F = 5 mA	2.7	3.2		V
			V_{CC} = 20 V, I_O = –2.6 mA, I_F = 5 mA	17.4	18.7		
	Low Level Output Voltage *2	V_{OL}	I_O = 3.5 mA, I_F = 0 mA		0.25	0.6	V
	High Level Supply Current	I_{CCH}	V_{CC} = 4.5 V, I_F = 5 mA		0.98	3	mA
			V_{CC} = 20 V, I_F = 5 mA		1.32	3	
	Low Level Supply Current	I_{CCL}	V_{CC} = 4.5 V, I_F = 0 mA		1.23	3	mA
			V_{CC} = 20 V, I_F = 0 mA		1.53	3	
	High Level Output Short *3 Circuit Current	I_{OSH}	V_{CC} = 4.5 V, V_O = GND, I_F = 5 mA	–7	–45		mA
	Low Level Output Short *3 Circuit Current	I_{OSL}	V_{CC} = V_O = 4.5 V, V_F = 0 V	7	34		mA
Coupled	Threshold Input Current	I_{FLH}	V_{CC} = 4.5 V, V_O > 2.7 V, I_O = –2.6 mA		1.52	3	mA
	Isolation Resistance	R_{I-O}	V_{I-O} = 1 kV_{DC}, RH = 60%, T_A = 25°C	10^{11}			Ω
	Isolation Capacitance	C_{I-O}	V = 0 V, f = 1 MHz, T_A = 25°C		0.6		pF
	Propagation Delay Time (H → L)*4	t_{PHL}	C_L = 15 pF, I_F = 5 → 0 mA, V_{THHL} = 1.3 V		108	200	ns
	Propagation Delay Time (L → H)*4	t_{PLH}	C_L = 15 pF, I_F = 0 → 5 mA, V_{THLH} = 1.3 V		121	200	ns
	Pulse Width Distortion (PWD)	$\lvert t_{PLH}-t_{PHL} \rvert$	C_L = 15 pF, I_F = 5 ↔ 0 mA		13	80	ns
	Maximum Propagation Delays (PDD)					100	ns
	Rise Time (10-90%)*4	t_r	C_L = 15 pF, I_F = 0 → 5 mA		25		ns
	Fall Time (90-10%)*4	t_f	C_L = 15 pF, I_F = 5 → 0 mA		4.6		ns
	Common Mode Transient Immunity at High Level Output*5	CM_H	V_{CC} = 5 V, T_A = 25°C, I_F = 5 mA, $\lvert V_{CM} \rvert$ = 1.5 kV	50			kV/μs
	Common Mode Transient Immunity at Low Level Output*5	CM_L	V_{CC} = 5 V, T_A = 25°C, I_F = 0 mA, $\lvert V_{CM} \rvert$ = 1.5 kV	50			kV/μs

Notes: *1. Typical values at T_A = 25°C

*2. Because V_O of 2.4 V may be output when the LED current is not input and when output supply of V_{CC} = 4.5 V or less, it is important to confirm the characteristics (operation with the power supply on and off) during design, before using this device.

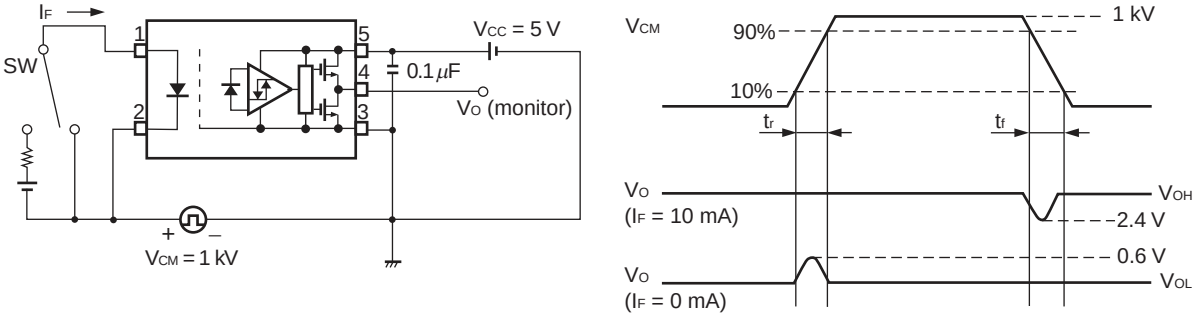
*3. Duration of output short circuit time should not exceed 10 ms.

*4. Test circuit for propagation delay time



Remark C_L includes probe and stray wiring capacitance.

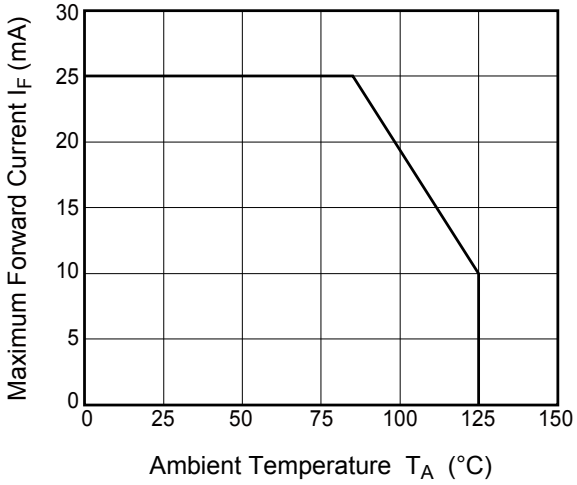
*5. Test circuit for common mode transient immunity



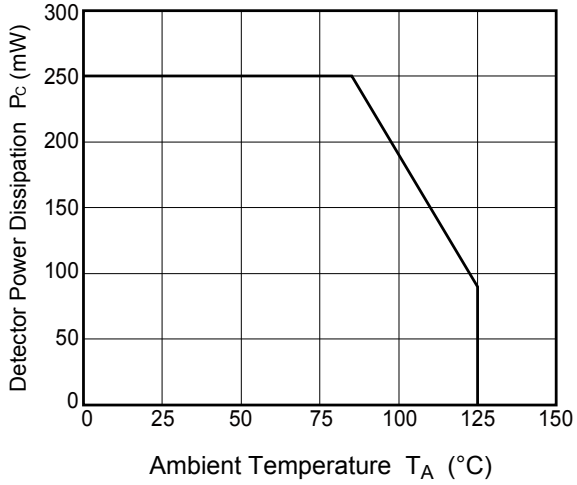
Remark C_L includes probe and stray wiring capacitance.

TYPICAL CHARACTERISTICS (T_A = 25°C, unless otherwise specified)

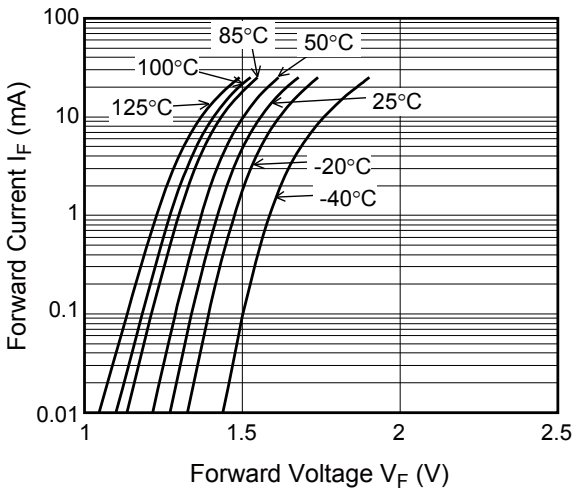
MAXIMUM FORWARD CURRENT vs. AMBIENT TEMPERATURE



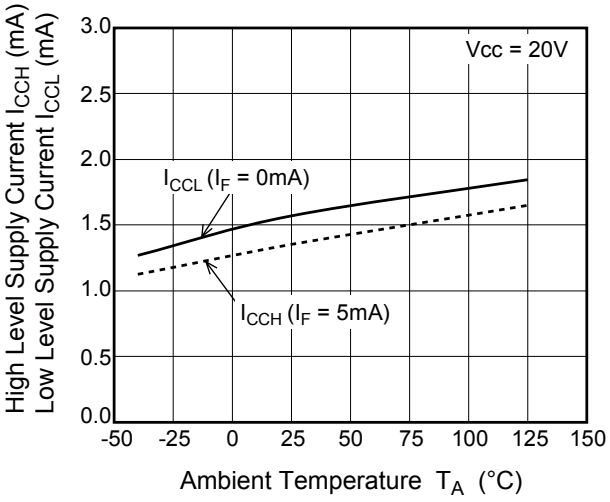
DETECTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



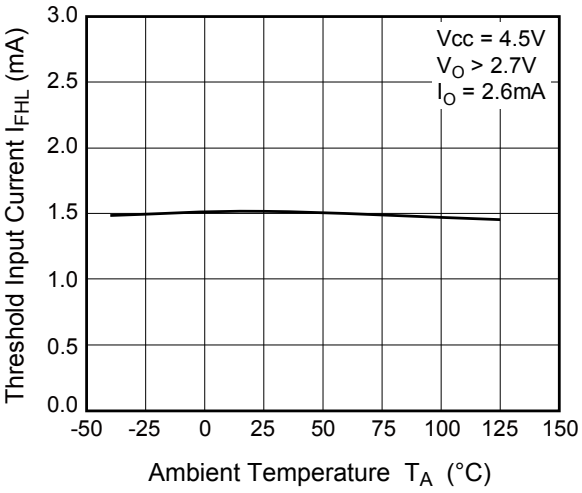
FORWARD CURRENT vs. FORWARD VOLTAGE



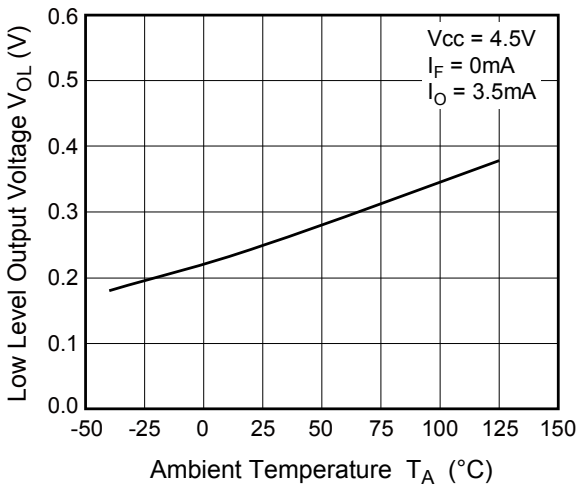
SUPPLY CURRENT vs. AMBIENT TEMPERATURE



THRESHOLD INPUT CURRENT vs. AMBIENT TEMPERATURE

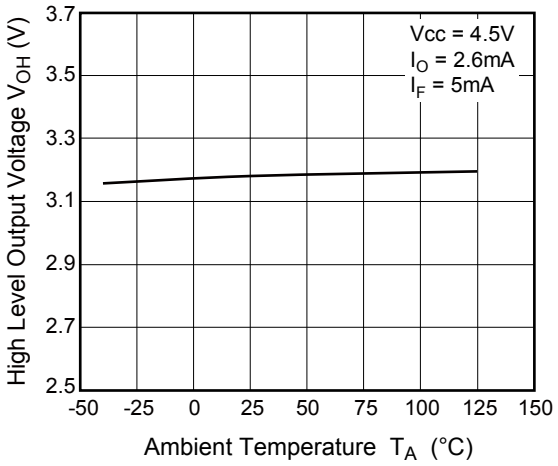


LOW LEVEL OUTPUT VOLTAGE vs. AMBIENT TEMPERATURE

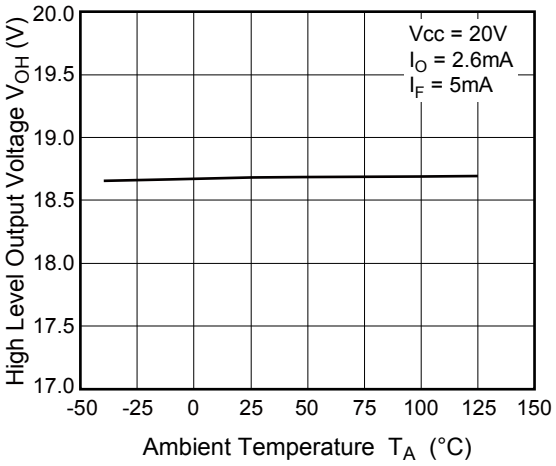


Remark The graphs indicate nominal characteristics.

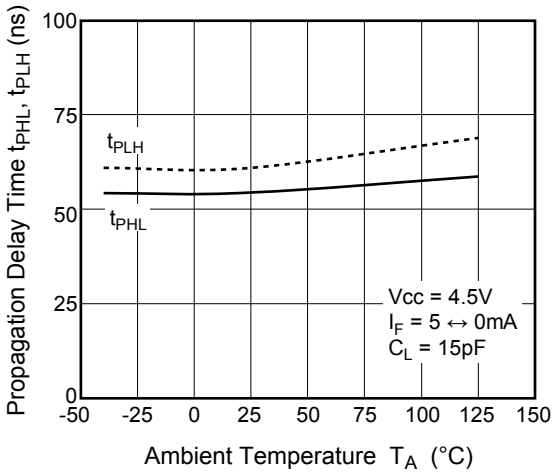
HIGH LEVEL OUTPUT VOLTAGE vs.
AMBIENT TEMPERATURE



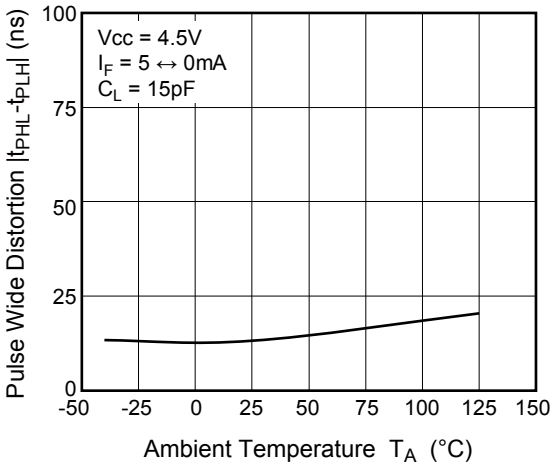
HIGH LEVEL OUTPUT VOLTAGE vs.
AMBIENT TEMPERATURE



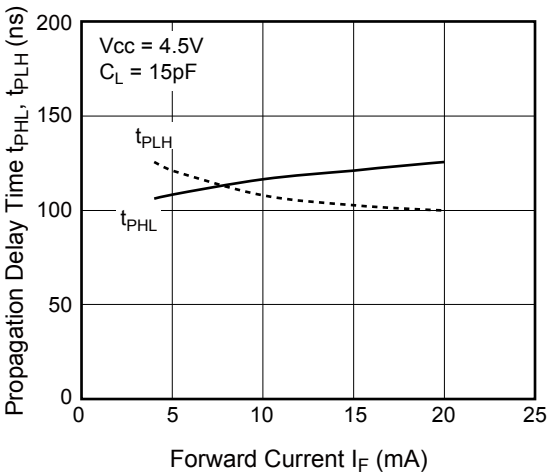
PROPAGATION DELAY TIME
vs. AMBIENT TEMPERATURE



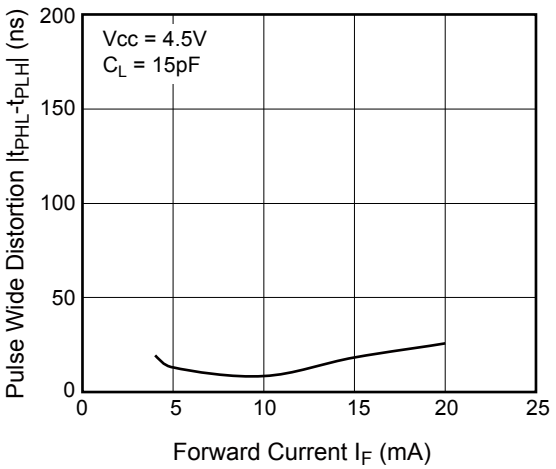
PULSE WIDE DISTORTION
vs. AMBIENT TEMPERATURE



PROPAGATION DELAY TIME
vs. FORWARD CURRENT

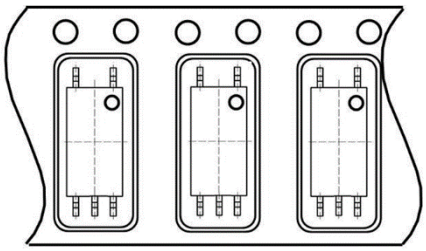


PULSE WIDE DISTORTION
vs. FORWARD CURRENT



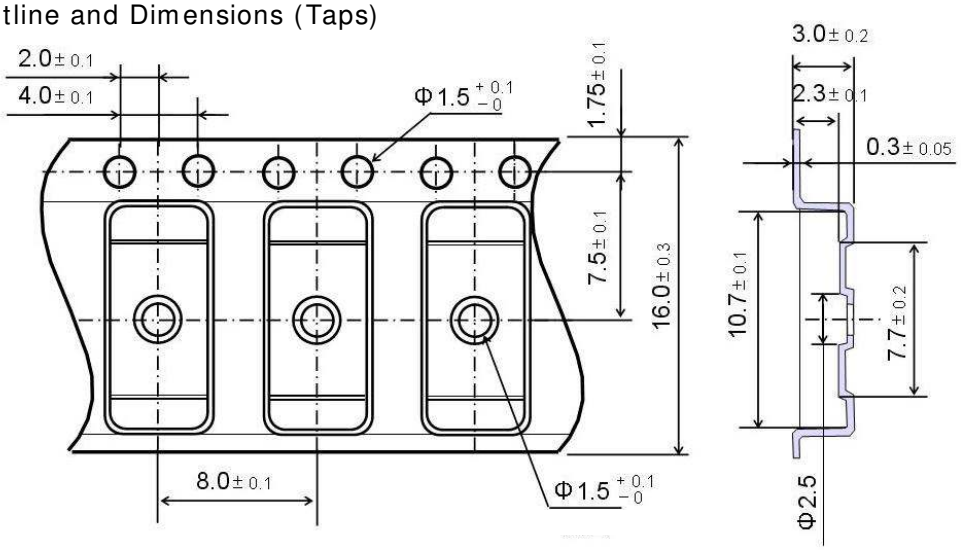
Remark The graphs indicate nominal characteristics.

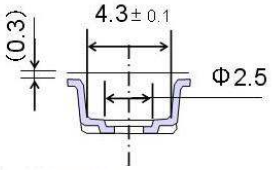
TAPING SPECIFICATIONS (UNIT: mm)



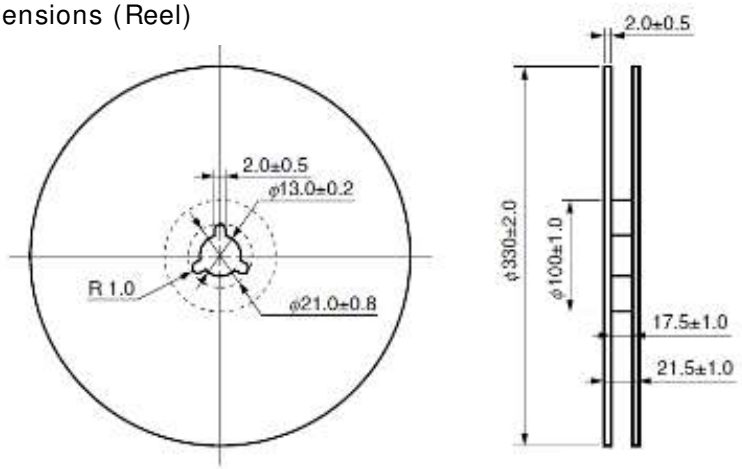
Tape Direction

Outline and Dimensions (Taps)



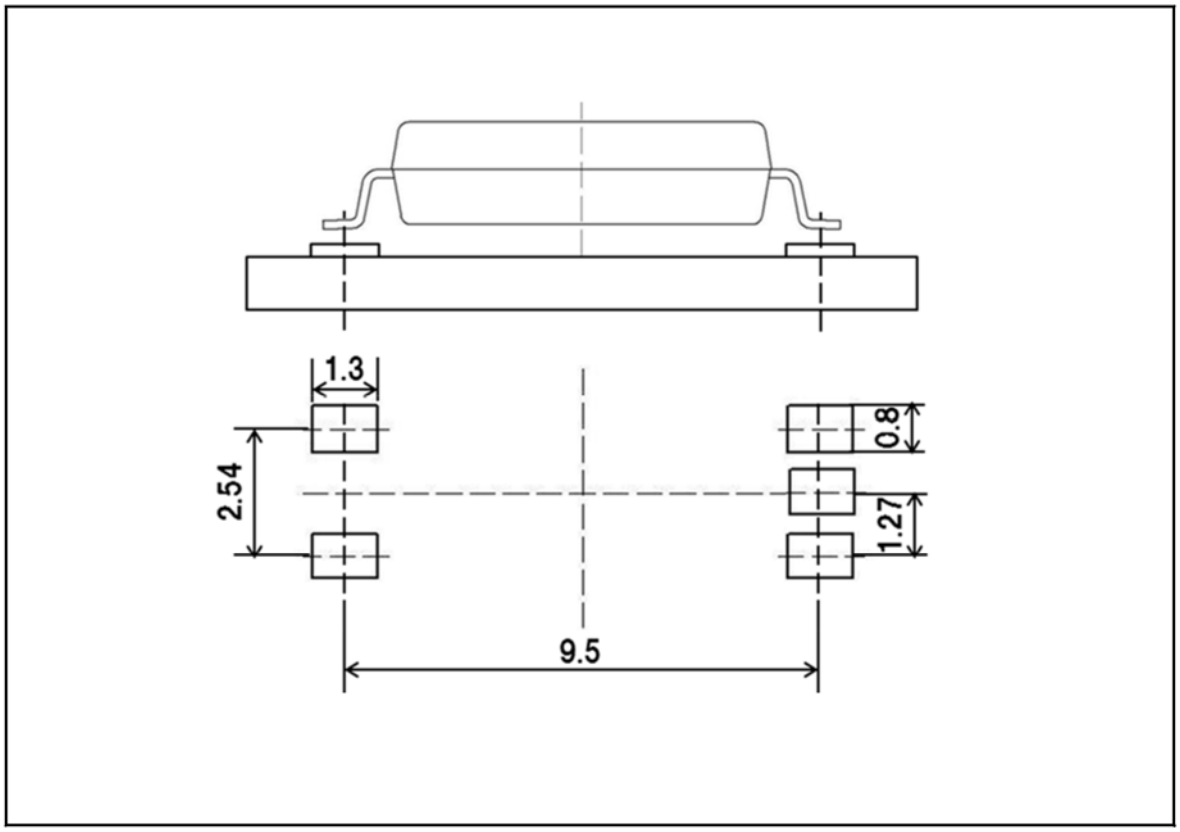


Outline and Dimensions (Reel)



Packing: 3000 pcs/reel

RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



Remark All dimensions in this figure must be evaluated before use.

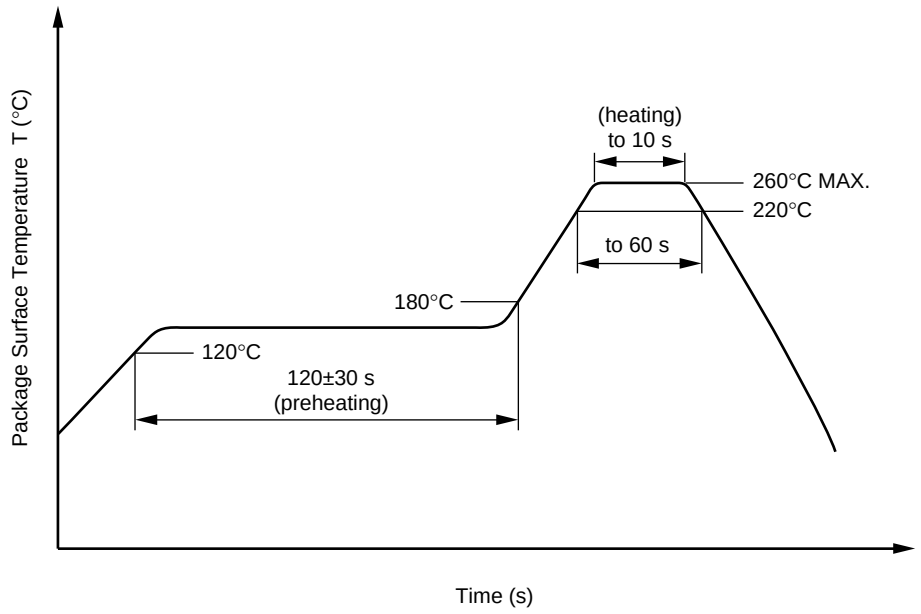
NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

• Peak reflow temperature	260°C or below (package surface temperature)
• Time of peak reflow temperature	10 seconds or less
• Time of temperature higher than 220°C	60 seconds or less
• Time to preheat temperature from 120 to 180°C	120±30 s
• Number of reflows	Three
• Flux	Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



(2) Wave soldering

• Temperature	260°C or below (molten solder temperature)
• Time	10 seconds or less
• Preheating conditions	120°C or below (package surface temperature)
• Number of times	One (Allowed to be dipped in solder including plastic mold portion.)
• Flux	Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

• Peak Temperature (lead part temperature)	350°C or below
• Time (each pins)	3 seconds or less
• Flux	Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead

(4) Cautions

• Fluxes	Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

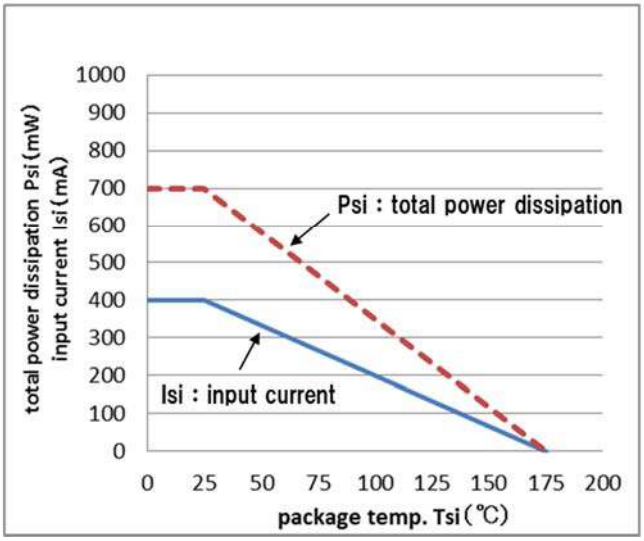
USAGE CAUTIONS

1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
2. By-pass capacitor of more than 0.1 μF is used between V_{CC} and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10 mm.
3. Avoid storage at a high temperature and high humidity.

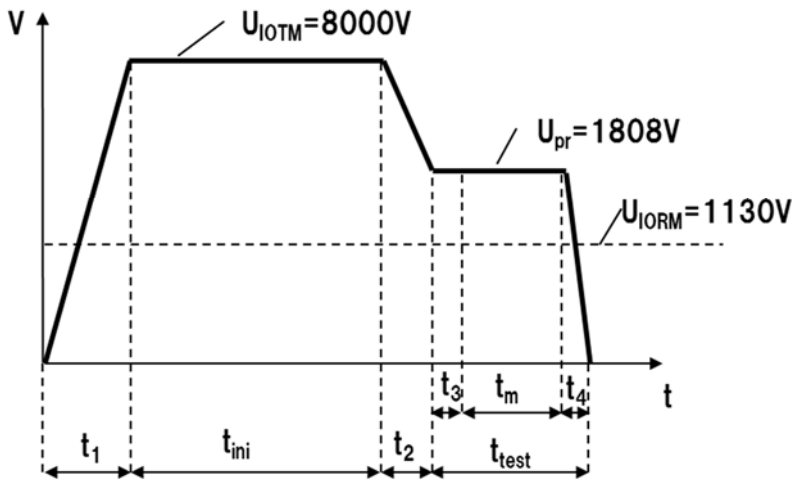
SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Spec.	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		40/125/21	
Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) U_{pr} = 1.6 × $U_{IORM.}$, P_d < 5 pC	 U_{IORM} U_{pr}	 1 130 1 808	 V_{peak} V_{peak}
Test voltage (partial discharge test, procedure b for all devices) U_{pr} = 1.875 × $U_{IORM.}$, P_d < 5 pC	U_{pr}	2 119	V_{peak}
Highest permissible overvoltage	U_{IOTM}	8 000	V_{peak}
Degree of pollution (DIN EN 60664-1 VDE0110 Part 1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303 Part 11))	CTI	400	
Material group (DIN EN 60664-1 VDE0110 Part 1)		II	
Storage temperature range	T_{stg}	–55 to +150	°C
Operating temperature range	T_A	–40 to +125	°C
Isolation resistance, minimum value V_{IO} = 500 V dc at T_A = 25°C V_{IO} = 500 V dc at T_A MAX. at least 100°C	 Ris MIN. Ris MIN.	 10^{12} 10^{11}	 Ω Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Package temperature Current (input current I_F, Psi = 0) Power (output or total power dissipation) Isolation resistance V_{IO} = 500 V dc at T_A = Tsi	 Tsi Isi Psi Ris MIN.	 175 400 700 10^9	 °C mA mW Ω

Dependence of maximum safety ratings with package temperature

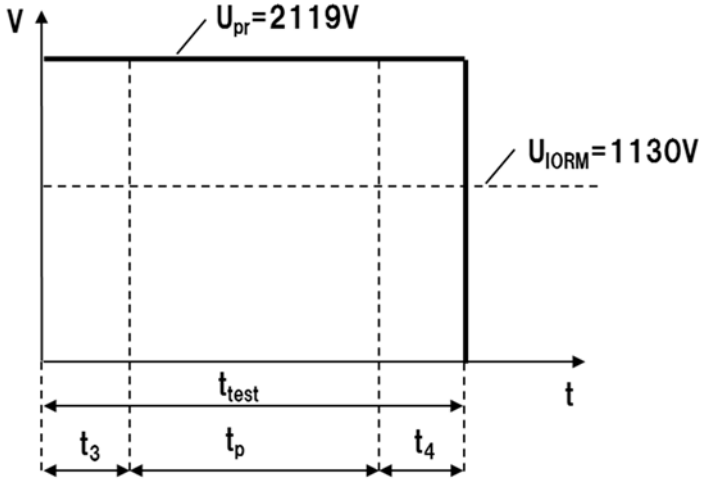


Method A Destructive Test, Type and Sample test



t_1,t_2=1 to 10 sec
t_3,t_4=1 sec
$t_{m\ (PARTIAL\ DISCHARGE)}$=10 sec
t_{test}=12 sec
t_{ini}=60 sec

Method b Non-destructive Test, 100% Production Test



t_3,t_4=0.1 sec
$t_{p\ (PARTIAL\ DISCHARGE)}$=1.0 sec
t_{test}=1.2 sec

Caution GaAs Products	This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points. • Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below. 1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials. 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal. • Do not burn, destroy, cut, crush, or chemically dissolve the product. • Do not lick the product or in any way allow it to enter the mouth.

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